# **Industrial Time Base Generator**

The MC14566B industrial time base generator is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. This device consists of a divide-by-10 ripple counter and a divide-by-5 or divide-by-6 ripple counter to permit stable time generation from a 50 or 60 Hz line. By cascading this device as divide-by-60 counters, seconds and minutes can be counted and are available in BCD format at the circuit outputs. An internal monostable multivibrator is included whose output can be used as a reset or clock pulse providing additional frequency flexibility. Also a pin has been included to allow divide-by-5 counting for generating 1.0 Hz from European 50 Hz line. Pin 11 =  $V_{DD}$  will cause  $\div$  5.

- Negative Edge Triggered Counters for Ease of Cascading
- Pulse Shapers on Counter Inputs Accept Slow Input Rise Times
- Monostable Multivibrator Positive or Negative Edge Triggered
- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range

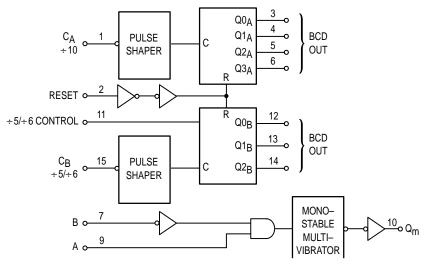
#### MAXIMUM RATINGS\* (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage	- 0.5 to + 18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage (DC or Transient)	$-0.5$ to $V_{DD} + 0.5$	٧
I <sub>in</sub> , I <sub>out</sub>	Input or Output Current (DC or Transient), per Pin	± 10	mA
PD	Power Dissipation, per Package†	500	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur. †Temperature Derating:

Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C Ceramic "L" Packages: – 12 mW/°C From 100°C To 125°C

### **BLOCK DIAGRAM**



# MC14566B



L SUFFIX CERAMIC CASE 620



P SUFFIX PLASTIC CASE 648



D SUFFIX SOIC CASE 751B

#### ORDERING INFORMATION

MC14XXXBCP Plastic MC14XXXBCL Ceramic MC14XXXBD SOIC

 $T_A = -55^{\circ}$  to 125°C for all packages.

#### **PIN ASSIGNMENT** 16 NDD RESET [ 15 ∏ C<sub>R</sub> 14 N Q2R Q0A 13 DQ1<sub>B</sub> Q1<sub>A</sub> [ 12 D Q0B Q2<sub>A</sub> Q3<sub>A</sub> 11 $1 \div 5/\div 6$ ВΠ 10 🛮 Q<sub>m</sub> V<sub>SS</sub> 🛘 8 9 🛮 A



**ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

Characteristic			V <sub>DD</sub>	– 55°C		25°C		125°C			
		Symbol	Vdc	Min	Max	Min	Тур#	Max	Min	Max	Unit
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level	VOL	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
$V_{in} = 0 \text{ or } V_{DD}$	"1" Level	VOH	5.0 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.0 10 15	_ _ _	4.95 9.95 14.95	_ _ _	Vdc
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	"0" Level	V <sub>IL</sub>	5.0 10 15	_ _ _	1.5 3.0 4.0		2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	Vdc
$(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level	VIH	5.0 10 15	3.5 7.0 11	_ _ _	3.5 7.0 11	2.75 5.50 8.25	_ _ _	3.5 7.0 11	=	Vdc
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	Source	ІОН	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	 	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	  -  -	- 1.7 - 0.36 - 0.9 - 2.4	_ _ _ _	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	lOL	5.0 10 15	0.64 1.6 4.2	_ _ _	0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4	_ _ _	mAdc
Input Current		l <sub>in</sub>	15	_	±0.1	_	±0.00001	±0.1	_	±1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)		C <sub>in</sub>	_	_	_	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		lDD	5.0 10 15	_ 	5.0 10 20	_ _ _	0.005 0.010 0.015	5.0 10 20	_ _ _	150 300 600	μAdc
Total Supply Current**† (Dynamic plus Quiesce Per Package) (C <sub>L</sub> = 50 pF on all outp buffers switching)		lΤ	5.0 10 15			$I_T = (2$	.0 μA/kHz) f 2.0 μA/kHz) f 3.0 μA/kHz) f	+ I <sub>DD</sub>			μAdc

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: IT is in  $\mu$ A (per package),  $C_L$  in pF,  $V = (V_{DD} - V_{SS})$  in volts, f in kHz is input frequency, and k = 0.001.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \le (V_{in} \text{ or } V_{out}) \le V_{DD}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must

be left open.

<sup>\*\*</sup> The formulas given are for the typical characteristics only at 25  $^{\circ}\text{C}.$ 

<sup>†</sup>To calculate total supply current at loads other than 50 pF:

## SWITCHING CHARACTERISTICS\* ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}C$ )

Characteristic	Symbol	V <sub>DD</sub>	Min	Typ #	Max	Unit
Output Rise and Fall Time  t <sub>TLH</sub> , t <sub>THL</sub> = (1.5 ns/pF) C <sub>L</sub> + 25 ns  t <sub>TLH</sub> , t <sub>THL</sub> = (0.75 ns/pF) C <sub>L</sub> + 12.5 ns  t <sub>TLH</sub> , t <sub>THL</sub> = (0.55 ns/pF) C <sub>L</sub> + 9.5 ns	t <sub>TLH</sub> , t <sub>THL</sub>	5.0 10 15	_ _ _	100 50 40	200 100 80	ns
Propagation Delay Time, Clock to Q3 <sub>A</sub> tp <sub>LH</sub> , tp <sub>HL</sub> = (1.7 ns/pF) C <sub>L</sub> + 1365 ns  tp <sub>LH</sub> , tp <sub>HL</sub> = (0.66 ns/pF) C <sub>L</sub> + 497 ns  tp <sub>LH</sub> , tp <sub>HL</sub> = (0.5 ns/pF) C <sub>L</sub> + 295 ns	t <sub>PLH</sub> , t <sub>PHL</sub>	5.0 10 15	_ _	1450 530 320	4500 1500 1000	ns
Propagation Delay Time, Reset to Q3 <sub>A</sub> $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 845 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 282 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 185 \text{ ns}$	<sup>t</sup> PHL	5.0 10 15	_ _ _	930 315 210	3000 1000 750	ns
Clock Pulse Width	<sup>t</sup> WH(cl)	5.0 10 15	1200 400 270	400 125 90	_ _ _	ns
Reset Pulse Width	<sup>t</sup> WH(R)	5.0 10 15	1200 400 270	400 125 90	_ _ _ _	ns
Clock Pulse Frequency	f <sub>Cl</sub>	5.0 10 15	_ _ _	1.0 2.5 4.2	0.3 1.0 1.5	MHz
Clock Pulse Rise and Fall Time	t <sub>TLH</sub> , t <sub>THL</sub>	5.0 10 15		No Limit		_
Monostable Multivibrator Pulse Width	<sup>t</sup> WH(Q <sub>m</sub> )	5.0 10 15	1200 400 300	2800 900 600	_ _ _	ns

<sup>\*</sup> The formulas given are for the typical characteristics only at 25°C.

<sup>#</sup>Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

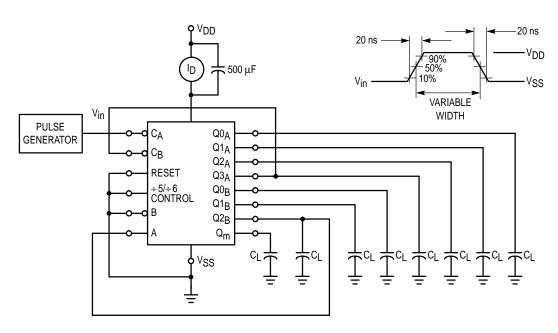
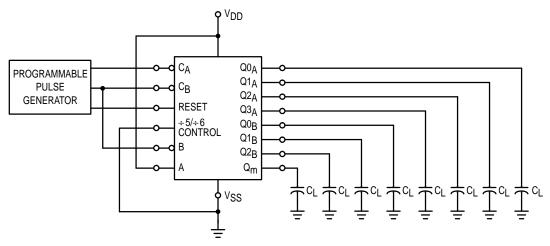


Figure 1. Power Dissipation Test Circuit and Waveform



NOTE: Assume  $\div$  10 Counter at "6" and  $\div$  5/  $\div$  6 Counter at "2" at beginning of sequence.

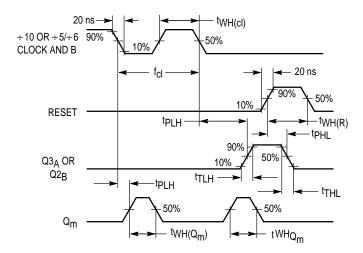
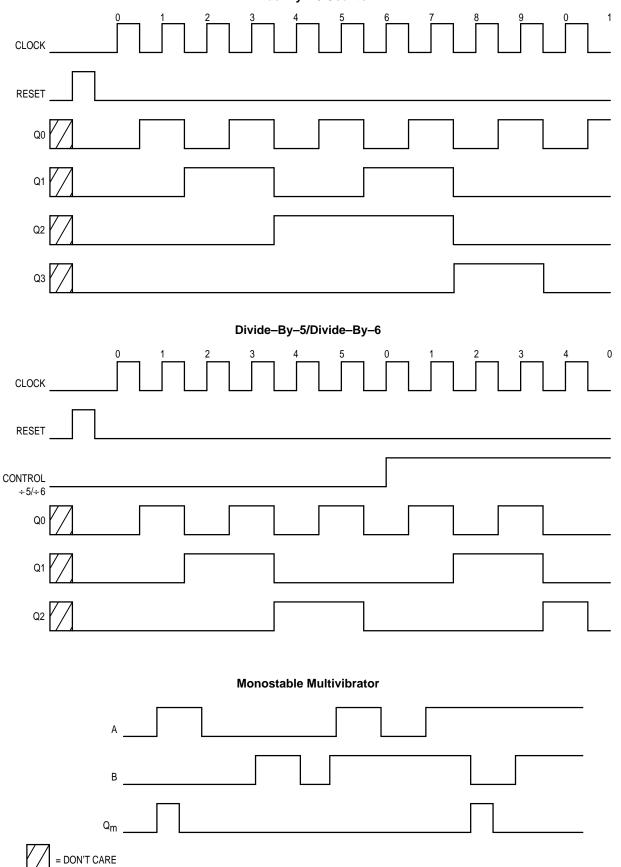


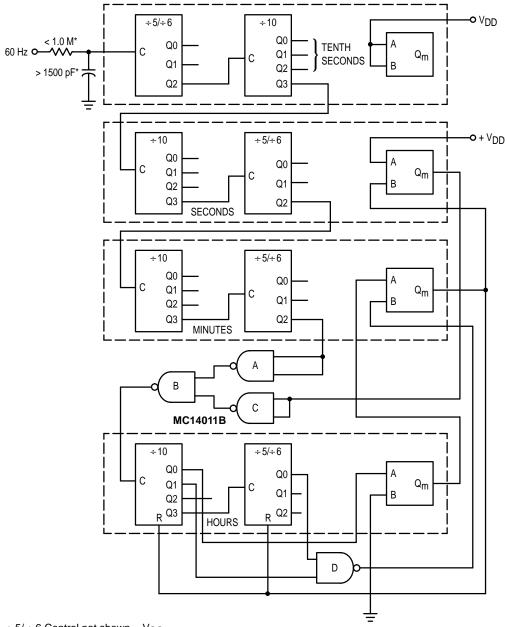
Figure 2. Switching Time Test Circuit and Waveforms

## **TIMING DIAGRAM**

## Divide-By-10 Counter



## **APPLICATION — 12 HOUR CLOCK**



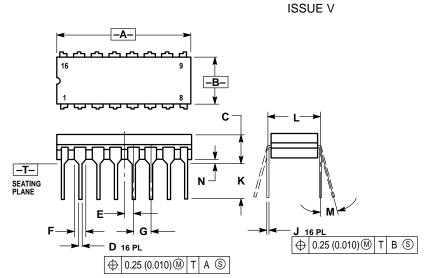
 $\div$  5/  $\div$  6 Control not shown = V<sub>SS</sub>

Reset pins not shown =  $V_{SS}$ 

\* Care must be taken in the indicated circuit to filter line transients which may cause "false" counting.

### **OUTLINE DIMENSIONS**

## **L SUFFIX** CERAMIC DIP PACKAGE CASE 620-10



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

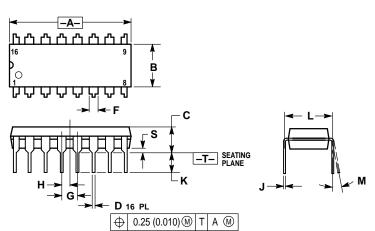
  3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

  4. DIMENSION F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC RODY.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
C		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050 BSC		1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100 BSC		2.54 BSC		
Н	0.008	0.015	0.21	0.38	
K	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
M	0 °	15°	0 °	15°	
N	0.020	0.040	0.51	1.01	

## **P SUFFIX**

PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIMETERS			
DIM	MIN	MAX	MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54 BSC			
Н	0.050	BSC	1.27 BSC			
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
M	0°	10°	0°	10 °		
S	0.020	0.040	0.51	1.01		

#### **OUTLINE DIMENSIONS**



- DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

  MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
Κ	0.10	0.25	0.004	0.009	
М	0°	7°	0°	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

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